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September 2003



FDG6332C 20V N & P-Channel PowerTrench[®] MOSFETs

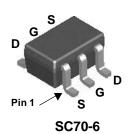
General Description

The N & P-Channel MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive TSSOP-8 and SSOP-6 packages are impractical.

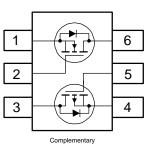
Applications

- DC/DC converter
- Load switch
- LCD display inverter



Features

- Q1 0.7 A, 20V. $\begin{array}{c} R_{DS(ON)} = 300 \mbox{ m}\Omega \ @ \ V_{GS} = 4.5 \ V \\ R_{DS(ON)} = 400 \mbox{ m}\Omega \ @ \ V_{GS} = 2.5 \ V \end{array}$
- Q2 -0.6 A, -20V.
 $$\begin{split} R_{DS(ON)} = 420 \ m\Omega \ @ \ V_{GS} = -4.5 \ V \\ R_{DS(ON)} = 630 \ m\Omega \ @ \ V_{GS} = -2.5 \ V \end{split}$$
- Low gate charge
- High performance trench technology for extremely low R_{DS(ON)}
- SC70-6 package: small footprint (51% smaller than SSOT-6); low profile (1mm thick)



Absolute Maximum Ratings $__{T_A=25^\circ C \text{ unless otherwise noted}}$

Symbol		Parameter		Q1	Q2	Units	
V _{DSS}	Drain-Sour	ce Voltage		20 –20		V	
V _{GSS}	Gate-Sourc	e Voltage		±12	±12 ±12		
ID	Drain Curre	ent – Continuous	(Note 1)	0.7	-0.6	А	
		 Pulsed 		2.1	-2		
PD	Power Diss	ipation for Single Opera	tion (Note 1)	(W		
T _J , T _{STG}	Operating a	and Storage Junction Te	mperature Range	–55 t	°C		
Therma	l Charac	teristics					
$R_{ ext{ hetaJA}}$	Thermal Re	esistance, Junction-to-A	mbient (Note 1)	4	°C/W		
Packag	e Markin	g and Ordering	Information				
Device Marking		Device	Reel Size	Tape width		Quantity	
.32		FDG6332C	7"	8mm		3000 units	

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Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted Symbol Min Max Units Parameter **Test Conditions** Тур **Off Characteristics** 20 V $V_{GS} = 0 V$, $I_{D} = 250 \ \mu A$ Q1 **BV**_{DSS} Drain-Source Breakdown Voltage $V_{GS} = 0 V$, $I_{D} = -250 \ \mu A$ Q2 -20 $I_D = 250 \,\mu\text{A},\text{Ref. to } 25^\circ\text{C}$ Breakdown Voltage Temperature ΔBV_{DSS} Q1 mV/°C 14 Coefficient $\Delta T_{\rm J}$ $I_D = -250 \ \mu A$, Ref. to $25^{\circ}C$ Q2 -14 $V_{DS} = 16 V$, $V_{GS} = 0 V$ Q1 1 μΑ Zero Gate Voltage Drain Current IDSS $V_{GS} = 0 V$ Q2 $V_{DS} = -16 V$, -1 I_{GSSF} / I_{GSSR} Gate-Body Leakage, Forward $V_{GS}=\pm \ 12 \ V, \quad V_{DS}=0 \ V$ ±100 nA $V_{GS}=\pm~12V~,~~V_{DS}=0~V$ I_{GSSF} /I_{GSSR} Gate–Body Leakage, Reverse ±100 nΑ On Characteristics (Note 2) $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ 0.6 V $V_{GS(th)}$ Gate Threshold Voltage Q1 1.1 1.5 $V_{DS} = V_{GS}, I_D = -250 \ \mu A$ -0.6 -1.2 -1.5 Q2 $\Delta V_{GS(th)}$ Gate Threshold Voltage $I_D = 250 \ \mu\text{A}$, Ref. To 25°C -2.8 mV/°C Q1 **Temperature Coefficient** ΔT_{J} Q2 $I_D = -250 \ \mu$ A,Ref. to 25° C 3 $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 0.7 \text{ A}$ 180 300 $R_{\text{DS(on)}}$ Static Drain-Source mΩ Q1 $V_{GS} = 2.5 \text{ V}, \quad I_D = 0.6 \text{ A}$ 400 293 **On-Resistance** $V_{GS} = 4.5 \text{ V}, \quad I_D = 0.7 \text{A}, T_J = 125^{\circ} \text{C}$ 442 247 $V_{GS} = -4.5 \text{ V}, I_D = -0.6 \text{ A}$ 300 420 Q2 $V_{GS} = -2.5 \text{ V}, I_D = -0.5 \text{ A}$ 470 630 V_{GS} =-4.5 V, I_D =-0.6 A, T_J =125°C 700 400 $V_{DS} = 5 V$ $I_{D} = 0.7 \text{ A}$ Forward Transconductance 2.8 S Q1 **G**FS $I_{\rm D} = -0.6A$ $V_{DS} = -5 V$ Q2 1.8 On-State Drain Current $V_{GS}=4.5~V, \quad V_{DS}=5~V$ Q1 1 А I_{D(on)} $V_{GS} = -4.5 \ V, \ V_{DS} = -5 \ V$ Q2 -2 **Dynamic Characteristics** \mathbf{C}_{iss} V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz Input Capacitance Q1 113 pF V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz Q2 114 V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz Coss **Output Capacitance** Q1 34 pF V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz Q2 24 V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz C_{rss} **Reverse Transfer Capacitance** Q1 16 pF V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz 9 Q2 Switching Characteristics (Note 2) Turn-On Delay Time 5 10 Q1 t_{d(on)} For **Q1**: ns V_{DS} =10 V, $I_{D} = 1 A$ 5.5 11 Q2 $V_{\text{GS}}\text{=} 4.5 \text{ V}, \quad \text{R}_{\text{GEN}} \text{=} 6 \ \Omega$ 7 15 tr Turn-On Rise Time Q1 ns Q2 For **Q2**: 14 25 $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ A}$ Turn-Off Delay Time Q1 9 18 ns t_{d(off)} V_{GS} = -4.5 V, R_{GEN} = 6 Ω Q2 6 12 Turn-Off Fall Time 3 Q1 1.5 tf ns Q2 1.7 3.4 Q_q **Total Gate Charge** Q1 1.1 1.5 nC For Q1: Q2 V_{DS}=10 V, I_D= 0.7 A 1.4 2 V_{GS} = 4.5 V, R_{GEN} = 6 Ω 0.24 Q1 Q_{gs} Gate-Source Charge nC For **Q2**: 0.3 Q2 $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.6 \text{ A}$ Q_{ad} Gate-Drain Charge Q1 0.3 nC V_{GS} = -4.5 V, R_{GEN} = 6 Ω Q2 0.4

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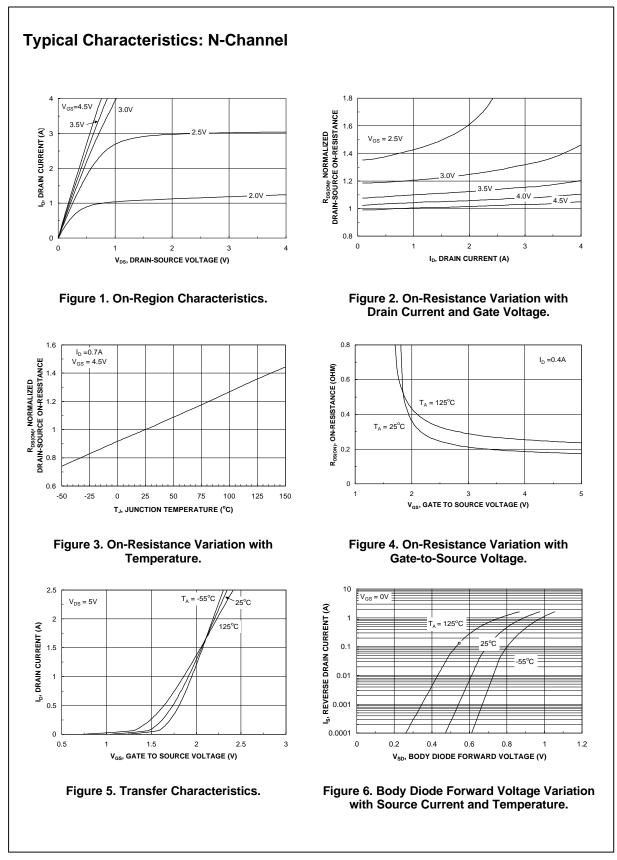
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						_		
Symbol	Parameter		Test Conditions	Min	Тур	Max	Units	
Drain–S	ource Diode Characteris	tics a	Ind Maximum Ratings					
ls	Maximum Continuous Drain-Se	-Source Diode Forward Current Q1				0.25	А	
		00			-0.25			
				Q2			-0.25	
V _{SD}	Drain–Source Diode Forward	Q1	$V_{GS} = 0 V$, $I_S = 0.25 A$ (N	ote 2)		0.74	1.2	V

Notes:

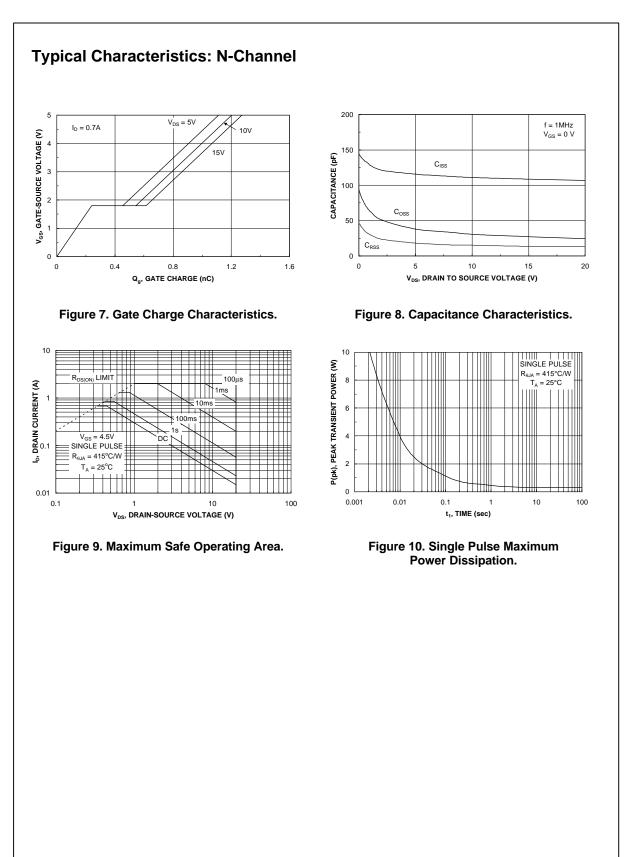
 R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{eJC} is guaranteed by design while R_{eJA} is determined by the user's board design. R_{eJA} = 415°C/W when mounted on a minimum pad of FR-4 PCB in a still air environment.

2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%

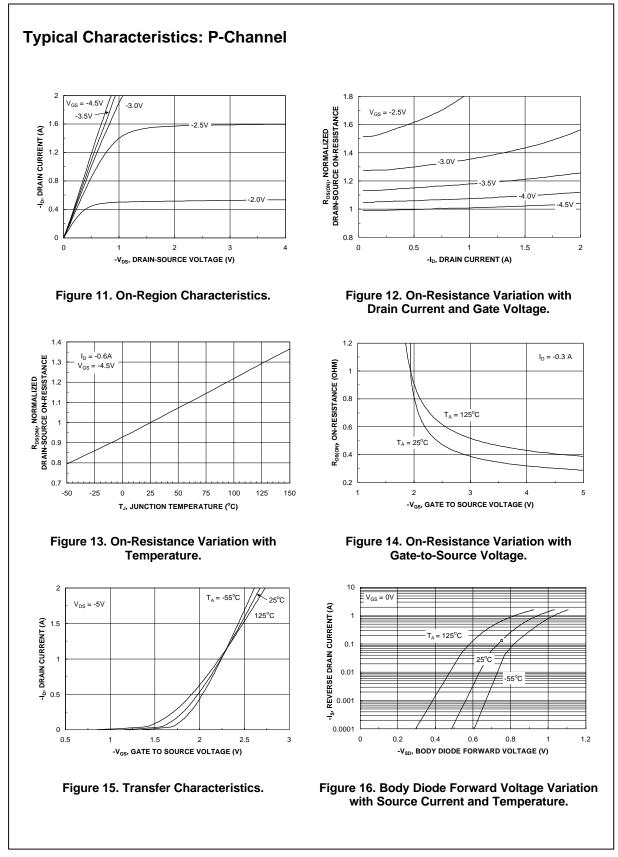


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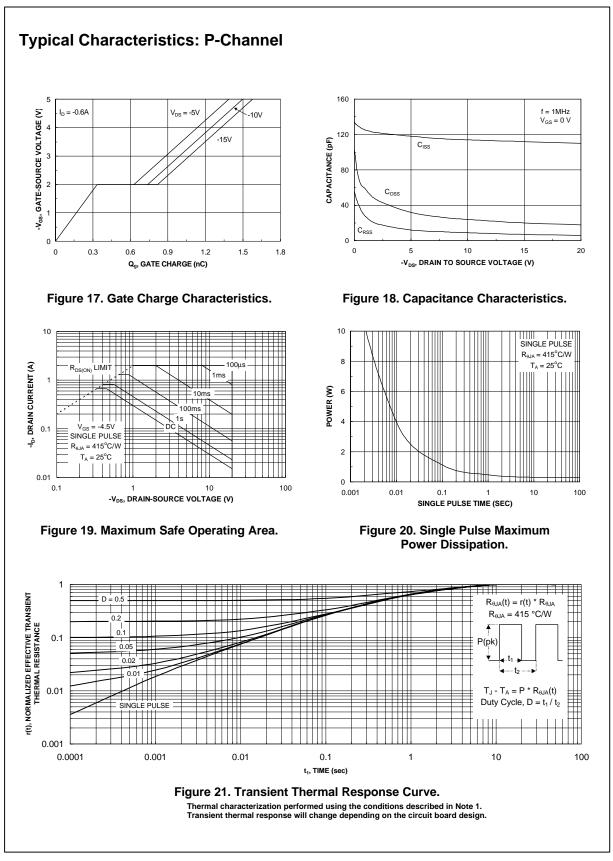
FDG6332C Rev C2 (W)





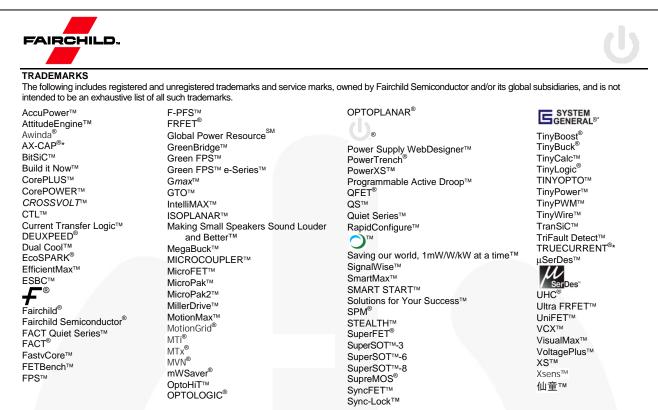


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